

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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BSR50

NPN Darlington Transistor

- This device designed for applications requiring extremely high gain at collector currents to 0.5A.
- · Sourced from Process 06.



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_A =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V _{CEO}	Collector-Emitter Voltage	45	V	
V _{CBO}	Collector-Base Voltage	60	V	
V _{EBO}	Emitter-Base Voltage	5	V	
I _C	Collector Current	1.5	Α	
T _J , T _{STG}	Storage Temperature	-55 ~ 150	°C	

Electrical Characteristics $T_A=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage *	$I_C = 10 \text{mA}, I_B = 0$	45			V
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_B = 0$	60			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 100 \mu A, I_C = 0$	5			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 45V, I_{E} = 0$			50	nA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 4.0V, I_{C} = 0$			50	nA
h _{FE}	DC Current Gain	V _{CE} = 10V, I _C = 150mA V _{CE} = 10V, I _C = 0.5A	1,000 2,000			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 500 \text{mA}, I_B = 500 \mu \text{A}$			1.3	V
\/ (aat)	Page Emitter Ceturation Voltage	I _C = 1.0A, I _B = 4.0mA			1.6	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = 500 \text{mA}, I_B = 500 \mu \text{A}$ $I_C = 1.0 \text{mA}, I_B = 4.0 \text{mA}$			0.9 2.2	V

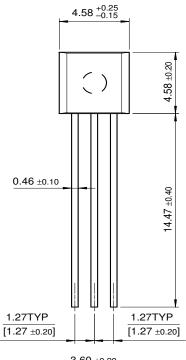
Thermal Characteristics $T_A=25$ °C unless otherwise noted

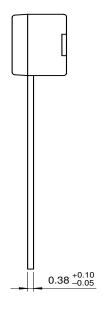
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation	625	mW
	Derate above 25°C	5.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case 83.3		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W

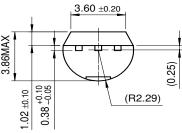
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Package Dimensions

TO-92







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	CoolFET™	FRFET™	MicroFET™	QFET®	SuperSOT™-8
	$CROSSVOLT^{\text{TM}}$	GlobalOptoisolator™	MicroPak™	QSTM	SyncFET™
	DOME™	GTO™ '	MICROWIRE™	QT Optoelectronics™	TinyLogic [®]
	EcoSPARK™	HiSeC™	MSX TM	Quiet Series™	TINYOPTO™
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	EnSigna™	i-Lo TM	OCX^{TM}	RapidConnect™	UHC™
	FACT™	ImpliedDisconnect™	OCXPro [™]	∞SerDes™	UltraFET®
	FACT Quiet Serie		OPTOLOGIC®	SILENT SWITCHER®	VCX TM
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Programmable Active Droop™

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Datasheet Identification	Product Status	Definition		
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Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.		
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